

Product Manual

EKWIN ELECTRONICS CO.,LTD

EK TN415

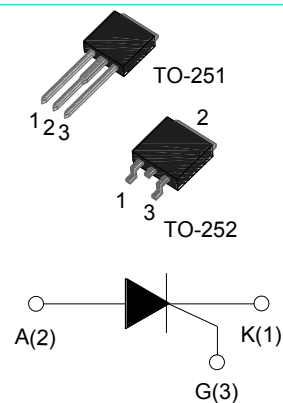
www.ekwin.net

 4A SCRs

TN415 Serial

Main Features:

IT(RMS)	VDRM/VRRM	VTM
4 A	600V and 800 V	≤1.8 V



Description:

Glass passivated, sensitive gate thyristors in a plastic envelope,intended for use in general purpose switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

Absolute Ratings(limiting values) :

Symbol	Parameter	value	Unit	
$I_{T(RMS)}$	on-state RMS current(180°C conduction angle)	4	A	
I_{TSM}	Non repetitive surge peak on-state current ($T_j = 25\text{ }^\circ\text{C}$)	$t_p = 8.3\text{ ms}$	38	A
		$t_p = 10\text{ ms}$	35	
V_{DRM}	Repetitive peak off-state voltage($T_j = 25\text{ }^\circ\text{C}$)	600 and 800	V	
V_{RRM}	Repetitive peak reverse voltage($T_j = 25\text{ }^\circ\text{C}$)	600 and 800	V	
T_{stg} T_j	Storage and operating junction temperature range	- 40 to + 150 - 40 to + 125	°C	
I^2t	I^2t value for fusing $T_j = 125\text{ }^\circ\text{C}$	$t_p = 10\text{ ms}$	6	A ² s
di/dt	Critical rate of rise of on-state current $I_G = 2xI_{GT}$, $t_r \leq 100\text{ns}$		50	A/μs

Electrical Characteristics :

Symbol	Test Condition	range	Value	Unit	
I_{GT}	V _D =12V R _L =3.3kΩ	T _j =25°C	MAX	20	mA
V_{GT}		T _j =25°C	MAX	1.5	V
V_{GD}	V _D =V _{DRM} R _L =3.3kΩ	T _j =125°C	MIN	0.2	V
t_{gt}	V _D =V _{DRM} I _G = 500mA dI _G /dt = 0.2A/μs	T _j =25°C	TYP	2	μs
I_L	V _D =12V I _{GT} = 0.1 A	T _j =25°C	TYP	0.17	mA
I_H	I _T = 500mA gate open	T _j =25°C	MAX	6	mA
V_{TM}	I _{TM} = 2*I _{T (RMS)} tp=380μs	T _j =25°C	MAX	1.8	V
I_{DRM} I_{RRM}	V _D =V _{DRM} , V _R =V _{RRM}	T _j =125°C	TYP	0.1	mA
		T _j =125°C	MAX	0.5	mA
dV_D/dt	V _D =67%V _{DR} exponential waveform; R _{GK} = 100 Ω	T _j =125°C	TYP	50	V/μs

Thermal Resistances :

Symbol	Parameter		Value	Unit
R_{th (j-c)}	junction to mounting case	TO-251/252	2.5	°C/W
R_{th (j-a)}	Junction to ambient	TO-251/252	60	K/W

Fig.1: Maximum average power dissipation versus average on-state current .

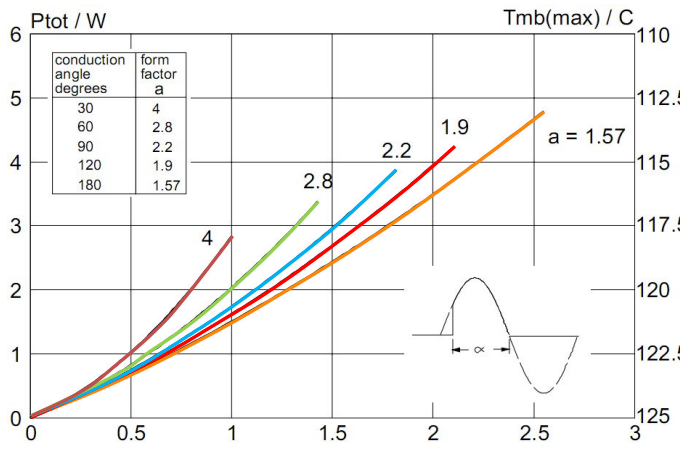


Fig.2 : Maximum permissible non-repetitive peak on-state current ITSM, versus pulse width tp, for sinusoidal currents, tp ≤ 10ms

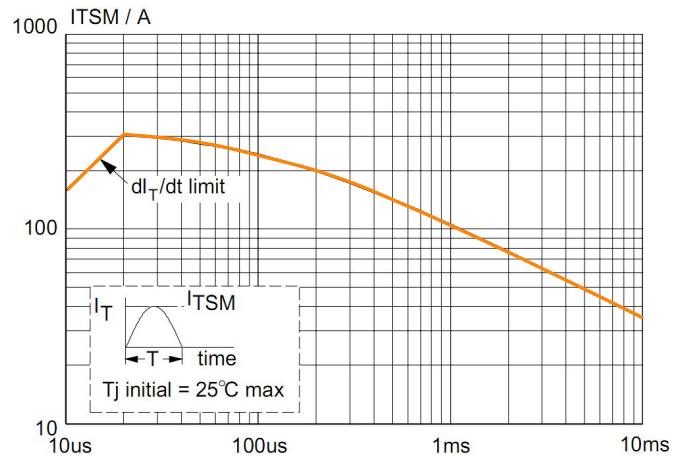


Fig.3 : Typical and maximum on-state characteristic.

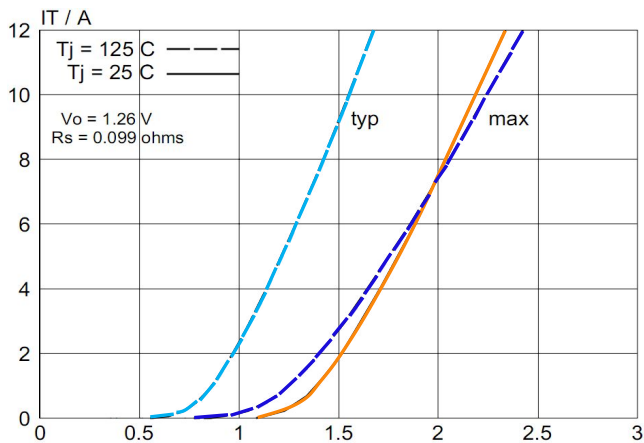


Fig.4 : Maximum permissible RMS current IT(RMS) , versus mounting base temperature Tmb.

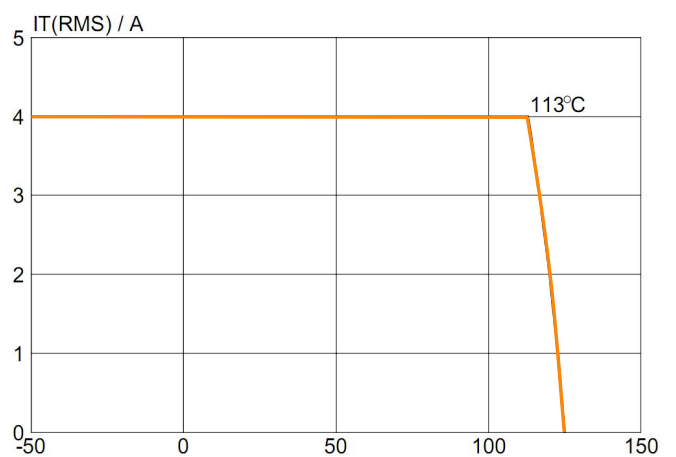


Fig.5 : Maximum permissible repetitive rms on-state current IT(RMS), versus surge duration, for sinusoidal currents, f = 50 Hz; Tmb ≤ 113°C

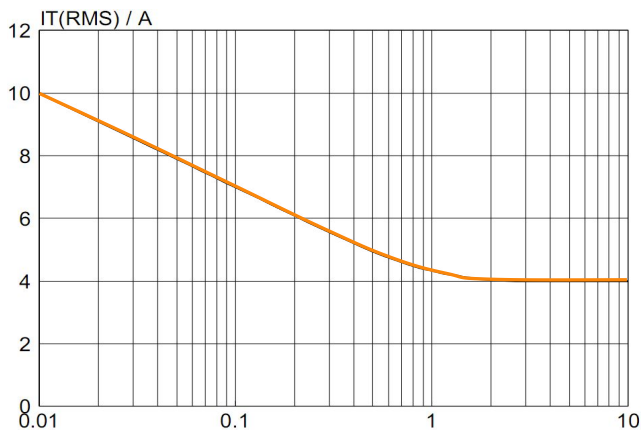


Fig.6: Normalised gate trigger voltage VGT(Tj)/ VGT(25 ° C), versus junction temperature Tj

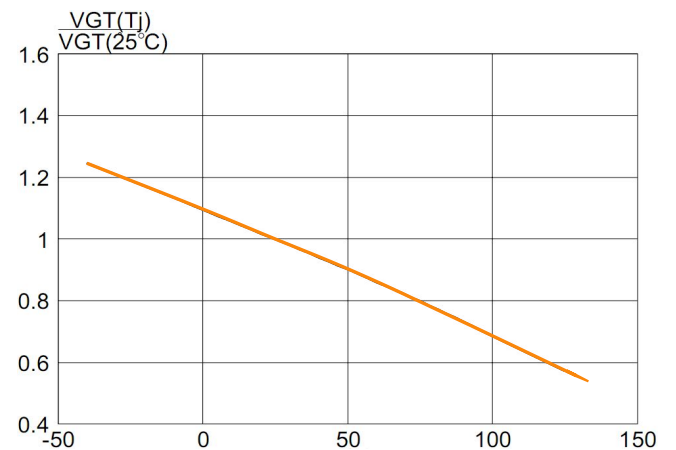


Fig.7 : Typical, critical rate of rise of off-state voltage, dV_D/dt versus junction temperature T_j

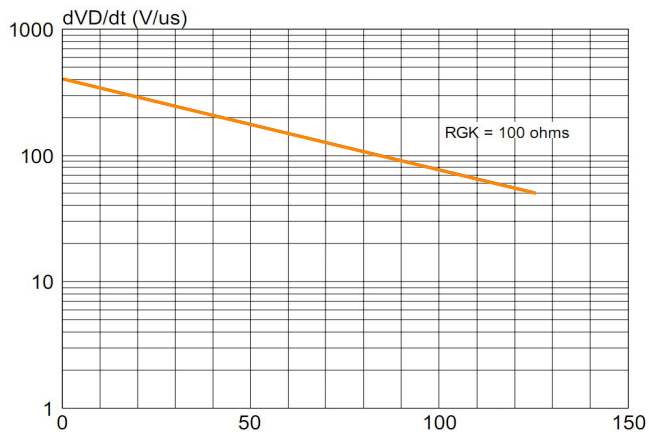
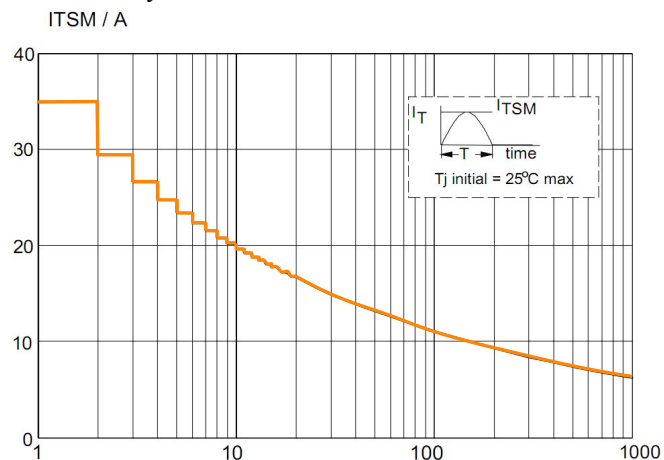
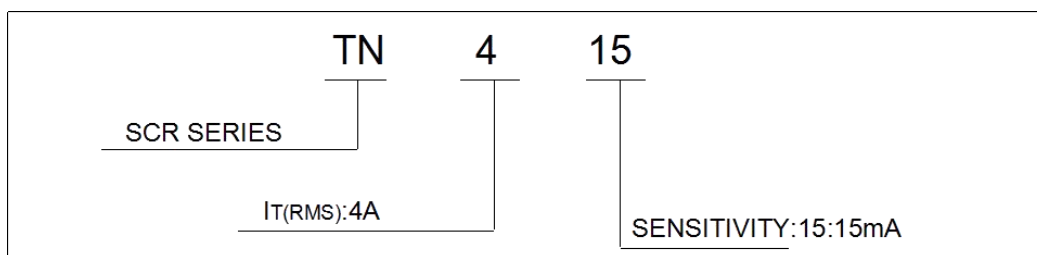


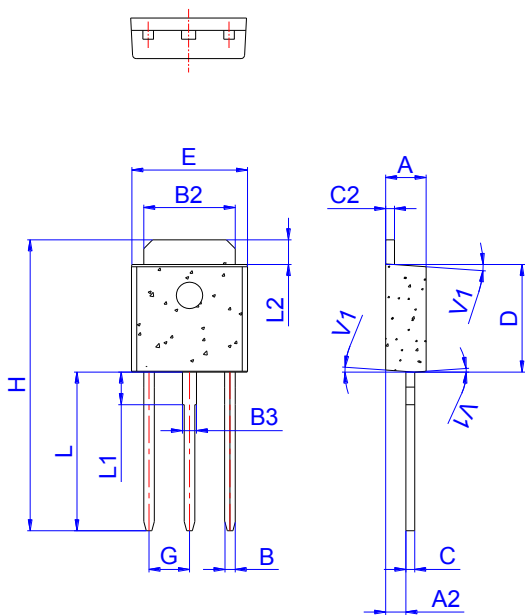
Fig.6: Non repetitive surge peak on-state current versus number of cycles.



Ordering Information

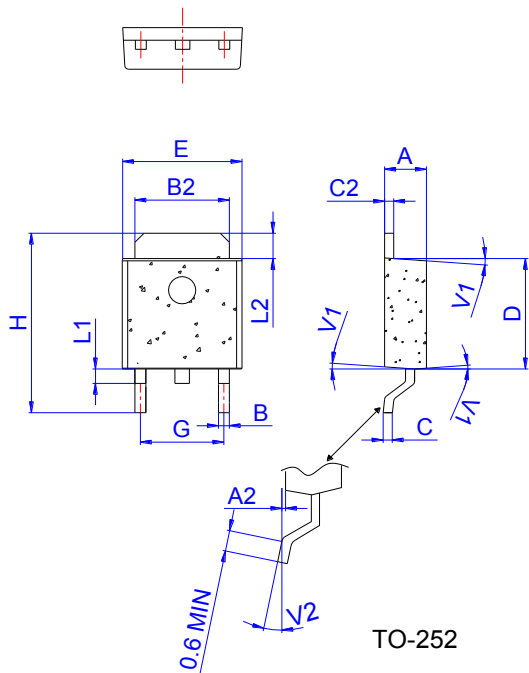


Package Mechanical Data :

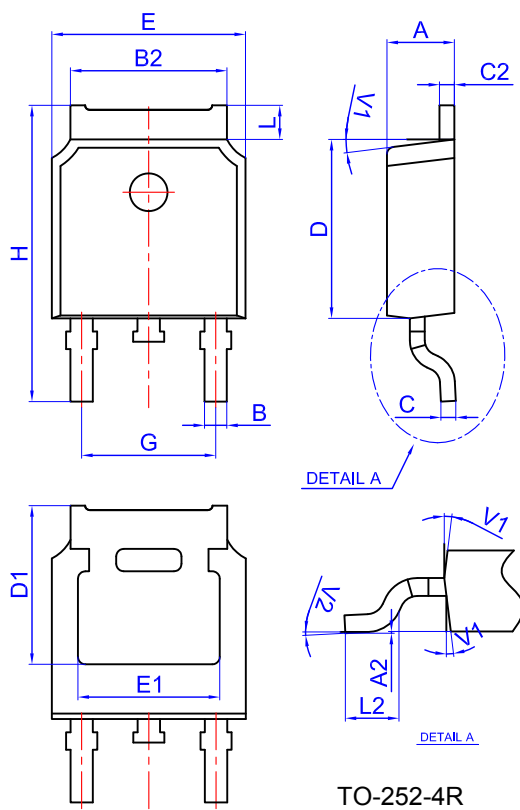


TO-251

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.90		1.20	0.035		0.047
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
B3	0.76		0.85	0.030		0.033
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G		2.30			0.091	
H	16.0		17.0	0.630		0.669
L	8.90		9.40	0.350		0.370
L1	1.80		1.90	0.071		0.075
L2	1.37		1.50	0.054		0.059
V1		4°			4°	



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.03		0.23	0.001		0.009
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G	4.40		4.70	0.173		0.185
H	9.35		10.6	0.368		0.417
L1	1.30		1.70	0.051		0.067
L2	1.37		1.50	0.054		0.059
V1		4°			4°	
V2	0°		8°	0°		8°



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°